

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	33	((ONO or O-N-O or (oxide near3 nitride near3 oxide)) near4 gate near4 (periph\$6 or HV or (high near2 volt\$6))) and cell	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 14:53
2	BRS	L2	3	alternating near4 ONO	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 13:21
3	BRS	L3	5	ONONO	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 13:24
4	BRS	L4	1859	flash and peripheral and code and substrate	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 13:24
5	BRS	L5	302	4 and insulating	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 13:25

	Type	L #	Hits	Search Text	DBs	Time Stamp
6	BRS	L6	34	ONO and 4	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 13:29
7	IS&R	L7	955	(438/151).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 13:29
8	IS&R	L10	2	("5412600").PN.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 14:01
9	IS&R	L11	2	("6417086").PN.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 14:01
10	IS&R	L12	843	(438/197).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 14:03

	Type	L #	Hits	Search Text	DBs	Time Stamp
11	IS&R	L13	2	("5994733").PN.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 14:05
12	IS&R	L14	2	("6291853").PN.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 14:06
13	BRS	L16	1392	(ONO or O-N-O or (oxide near3 nitride near3 oxide)) near4 (floating or control) near2 gate	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 14:54
14	BRS	L17	1020	16 and flash	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 14:54
15	BRS	L18	34	17 and code	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 14:56

	Type	L #	Hits	Search Text	DBs	Time Stamp
16	BRS	L19	11	18 and (@ad<20010626)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 14:56
17	IS&R	L21	1034	(438/585).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/04 15:59